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|  | <h2 style="color: #E67E22;">AON5802BL</h2> | |
| | Hersteller-Teilenummer: | AON5802BL |
|  <p>Not Actual Photo YIC International Co., Limited.</p> | Hersteller / Marke: | Alpha and Omega Semiconductor, Inc. |
| | Teil der Beschreibung: | MOSFET N-CH DUAL 30V 6DFN |
| | RoHs Status: | Bleifrei / RoHS-konform |
| | Lagerzustand: | New original, 1100 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

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|--|---|
| Teilenummer | AON5802BL |
| Hersteller | Alpha and Omega Semiconductor, Inc. |
| Beschreibung | MOSFET N-CH DUAL 30V 6DFN |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 1100 pcs Stock |
| detaillierte Beschreibung | Mosfet Array 2 N-Channel (Dual) Common Drain 30V |
| Serie | - |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Leistung - max | 1.6W |
| Verpackung / Gehäuse | 6-VDFN Exposed Pad |
| Supplier Device-Gehäuse | 6-DFN (2x5) |
| Typ FET | 2 N-Channel (Dual) Common Drain |
| FET-Merkmal | Standard |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 7.2A (Tc) |
| Rds On (Max) @ Id, Vgs | 19 mOhm @ 7A, 4.5V |
| VGS (th) (Max) @ Id | 1.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 24nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1150pF @ 15V |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

AON5802BL ist neu im Original, Suche AON5802BL Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie AON5802BL Alpha and Omega Semiconductor, Inc. mit Garantie und Vertrauen. Anfrage AON5802BL: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|--|
|  <p>AON5816 Alpha and Omega Semiconductor, Inc. MOSFET 2 N-CHANNEL 20V 12A 6DFN</p> |  <p>AON5802BL AOS AOS QFN</p> |  <p>AON5802ALS Alpha and Omega Semiconductor, Inc. MOSFET N-CH DUAL DFN</p> |  <p>AON5810 Alpha and Omega Semiconductor, Inc. MOSFET 2N-CH 20V 7.7A 6DFN</p> |
|  <p>AON5802AL AOS AON5802AL AOS</p> |  <p>AON5802B Alpha and Omega Semiconductor, Inc. MOSFET 2N-CH 30V 7.2A 6DFN</p> |  <p>AON5802B_101 Alpha and Omega Semiconductor, Inc. MOSFET N-CH DUAL DFN</p> |  <p>AON5802A Alpha and Omega Semiconductor, Inc. MOSFET 2N-CH 30V 7.2A 6-DFN</p> |

heiße Teile

Mehr

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|-------------|-------------|------------|-------------|--------------|
| ⊛ AON2701L | ↔ AON3402L | ⇒ AON3814L | D AON3814L | ⇒ AON4420L |
| ⊣ AON4701L | ⊛ AON4805L | D AON5802A | ⇒ AON5802AL | ⇒ AON5802ALS |
| ⊛ AON5802B | ⊣ AON5802BL | ⊛ AON6160S | ↔ AON6200L | ⇒ AON6202L |
| D AON6204L | ⊛ AON6232A | ⊣ AON6250A | ⊛ AON6262E | ⇒ AON6264E |
| ⇒ AON6290A | ↔ AON6338FH | ⊛ AON6366C | ⊣ AON6366E | ⇒ AON6366E |
| ↔ AON6400C | ⇒ AON6400L | D AON6402A | ⊛ AON6404A | ⊣ AON6404L |
| ⊛ AON6405L | D AON6408L | ⇒ AON6410L | ↔ AON6414A | ⇒ AON6414AL |
| ⊣ AON6414AL | ⊛ AON6416L | ↔ AON6418L | ⇒ AON6422L | ⇒ AON6426L |
| ⊛ AON6428L | ⊣ AON6440L | ⊛ AON6450L | D AON6452L | ⇒ AON6452L |
| ↔ AON6454A | ⊛ AON6506S | ⊣ AON6510A | ⊛ AON6532P | ⇒ AON6566P |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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